Voltage Regulators, Peak Power Zener Surge Rated, 600 Watt

BZG03C15 Series

The SMA series is supplied in ON Semiconductor's exclusive, cost-effective, highly reliable SURMETIC $^{\text{\tiny{TM}}}$ package and is ideally suited for use in communication systems, automotive, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications. This new line of 1.5 watt Zener diodes offers the following advantages:

Specification Features

- Standard Zener Breakdown Voltage 15 V to 150 V
- Peak Power 600 Watts @ 100 μs
- ESD Rating of Class 3 (> 16 KV) per Human Body Model
- Response Time is Typically < 1.0 ns
- Flat Handling Surface for Accurate Placement
- Package Design for Top Slide or Bottom Circuit Board Mounting
- Low Profile Package
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Mechanical Characteristics

CASE: Void-free, transfer-molded plastic

FINISH: All external surfaces are corrosion resistant and leads are readily solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

POLARITY: Cathode indicated by molded polarity notch or polarity

1

MOUNTING POSITION: Any



ON Semiconductor®

www.onsemi.com

PLASTIC SURFACE MOUNT ZENER VOLTAGE REGULATORS 600 WATTS PEAK POWER





SMA CASE 403D

MARKING DIAGRAM



XXX = Specific Device Code (See Table on Page 2)

A = Assembly Location

Y = Year WW = Work Week = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
BZG03C15G	SMA (Pb-Free)	5000/Tape & Reel
BZG03C150G	SMA (Pb-Free)	5000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

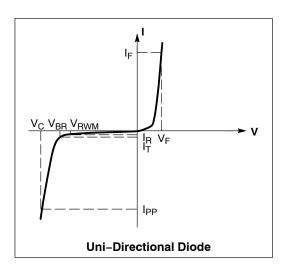
BZG03C15 Series

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation (Note 1) @ T _L = 25°C, t _P = 100 μs	P _{ZSM}	600	W
DC Power Dissipation @ T _L = 75°C Measured Zero Lead Length (Note 2) Derate Above 75°C Thermal Resistance, Junction–to–Lead	P _D	1.5 20 50	W mW/°C °C/W
Forward Surge Current (Note 3) @ T _A = 25°C	I _{FSM}	40	Α
Operating and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. $100 \, \mu s$, non-repetitive square pulse
- 2. 1 in. square copper pad, FR-4 board
- 3. 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute maximum



SYMBOLS DEFINITIONS

Symbol	Parameter		
I _{PP}	Maximum Reverse Peak Pulse Current		
V _C	Clamping Voltage @ I _{PP}		
V _{RWM}	Working Peak Reverse Voltage		
I _R	Maximum Reverse Leakage Current @ V _{RWM}		
V _{BR}	Breakdown Voltage @ I _T		
I _T	Test Current		
Ι _F	Forward Current		
V _F	Forward Voltage @ I _F		

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted, $V_F = 1.2 \text{ V Max.}$ @ $I_F = 0.5 \text{ A}$ for all types)

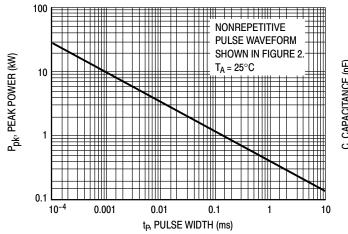
		V_{RWM}		Breakdown Voltage			Z _{zt} @ I _T		
	Device	(Note 4)	I _R @ V _{RWM}	② V _{RWM} V _{BR} (V) (Note 5)		e 5)	@ I _T	Тур	Max
Device*	Marking	Volts	μΑ	Min	Nom	Max	mA	Ω	Ω
BZG03C15, G	G15	11	1	13.8	15.0	15.6	50	5.0	10.0
BZG03C150, G	G150	110	1	138	150	156	5	130	300

^{4.} A transient suppressor is normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal to or greater than the DC or continuous peak operating voltage level

^{5.} V_{BR} measured at pulse test current I_T at an ambient temperature of 25°C *The "G" suffix indicates Pb–Free package available.

BZG03C15 Series

RATING AND TYPICAL CHARACTERISTIC CURVES



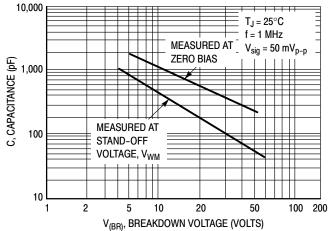
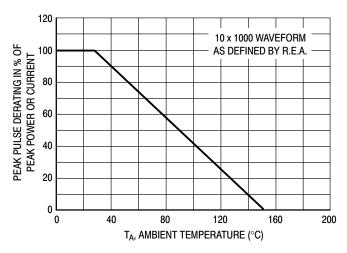
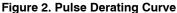


Figure 1. Pulse Rating Curve

Figure 3. Typical Junction Capacitance





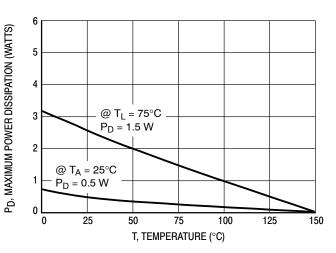


Figure 4. Steady State Power Derating

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STYLE 1 STYLE 2

SCALE 1:1

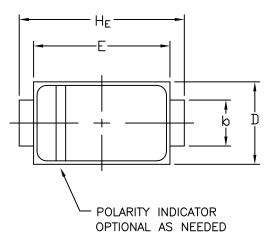


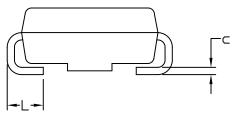
DATE 22 OCT 2021

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCHES
- 3. DIMENSION 6 SHALL BE MEASURED WITHIN DIMENSION L.

	MILLIMETERS			INCHES		
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
Α	1.97	2.10	2.20	0.078	0.083	0.087
A1	0.05	0.10	0.20	0.002	0.004	0.008
b	1.27	1.45	1.63	0.050	0.057	0.064
С	0.15	0.28	0.41	0.006	0.011	0.016
D	2.29	2.60	2.92	0.090	0.103	0.115
Ε	4.06	4.32	4.57	0.160	0.170	0.180
HE	4.83	5.21	5.59	0.190	0.205	0.220
L	0.76	1.14	1.52	0.030	0.045	0.060

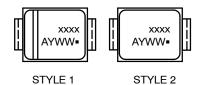




STYLE 1: STYLE 2: PIN 1. CATHODE (POLARITY BAND) NO POLARITY 2. ANODE

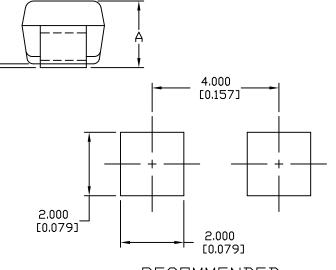
DDE (POLARITY BAND) NO POLARIT E

GENERIC MARKING DIAGRAM*



xxxx = Specific Device Code A = Assembly Location

Y = Year WW = Work Week ■ = Pb-Free Package



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